



# 25th RD50 Workshop (CERN)

## Wednesday, November 19, 2014

**Defect and Material Characterization - 500/1-001 - Main Auditorium (9:40 AM - 12:00 PM)**

**-Conveners: Ioana Pintilie**

time	[id] title	presenter
9:40 AM	[1] Nitrogen impact on vacancy aggregation in silicon single crystals	Mr KWESTARZ, Michael
10:00 AM	[2] First results on properties and concentrations of radiation defect centers in nitrogen-enriched, high-resistivity FZ silicon	Prof. KAMINSKI, Pawel
10:20 AM	[11] Point and extended defects in silicon induced by electron irradiation – dependence on the particle energy	Dr PINTILIE, Ioana
10:40 AM	Coffee Break	
11:10 AM	[20] Photoconductivity spectra as a tool for Si material stability control.	Prof. VAITKUS, Juozas
11:30 AM	[23] Discussion on Defect and Material Characterization	Dr PINTILIE, Ioana